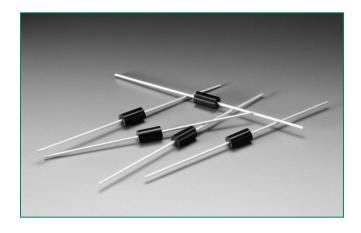
Littelfuse Expertise Applied | Answers Delivered

Kxxx1GL Series RoHS



Schematic Symbol



Applications

Typical application circuit presented in Figure 10 of this data sheet (Typical Metal Halide Ignitor Circuit).

Description

The Multipulse[™] SIDAC is a voltage switch used in Metal-Halide lamp ignition circuits, as well as High Pressure Sodium lamp ignition circuits for outdoor street and area lighting. This robust solid-state switch is designed to handle lamp igniter applications requiring operation at ambient temperatures up to 90°C where igniter circuit components can raise SIDAC junction temperature up to 125°C, especially when the lamp element is removed or ruptured. Its excellent commutation time (t_{COMM}) makes this robust product best suited for producing multiple pulses in each half cycle of 50/60 Hz line voltage. The Multipulse[™] SIDAC is offered in a DO-15 axial leaded package.

Kxxx1GL SIDAC has a repetitive off-state blocking voltage (V_{DRM}) of 180V to 270V minimum depending actual device type. Blocking capability is ensured by glass passivated junctions for best reliability. The package is epoxy encapsulated with tin plated copper alloy leads.

Features

- AC circuit oriented
- RoHS Compliant
- Triggering Voltage of 200 to 380V

Electrical Specifications

Symbol	Parameters	Test Conditions	Min	Max	Unit
V _T	On-state Voltage	IT=1A		3	V
I _{TRM}	Peak Non-Repetitive Surge Current	TA=25 °C Pulse Wave = 10µs, Sine Wave, f=120Hz		50	А
V _{BO}	Breakover/Trigger Voltage	K2201GL K2401GL K2501GL K3601GL	200 220 240 348	230 250 265 380	V
V_{DRM}	Repetitive Peak Off-State Voltage	K2201GL K2401GL K2501GL K3601GL	180 190 200 270		V
I _{T(RMS)}	On-State RMS Current, T _J < 125°C	50/60Hz Sine Wave		1	А
I _H	Dynamic Holding Current, R=100 Ω	50/60Hz Sine Wave		30 TYP	mA
R_s	Switching Resistance, $R_S = \frac{(V_{BO} - V_S)}{(I_S - I_{BO})}$	50/60Hz Sine Wave	100		Ω
t _{COMM}	Commutation Time T _J < 125°C	See test circuit and waveform in Figure 9		100	μsec
I _{BO}	Breakover Current	50/60Hz Sine Wave		10	uA
I _{TSM}	Non-repetitive 1 cycle On-State peak value	60Hz 50Hz		20.0 16.7	А
di/dt	Critical Rate of Rise of On-State Current			150	A/µsec
dv/dt	Critical Rate of Rise of Off-State Voltage			1500	V/µsec
T _s	Storage Temperature Range		-40	+125	°C



Figure 1: Characteristics

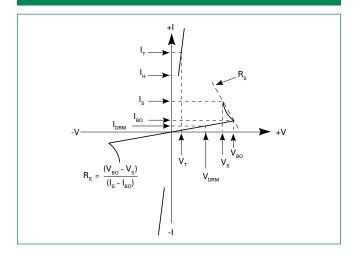


Figure 3: Power Dissipation (Typical) vs. On-State Current

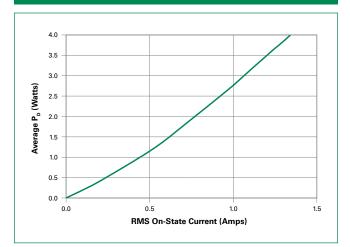


Figure 5: Pulse On-State Current Rating

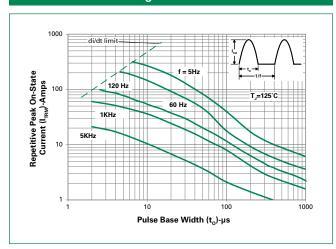


Figure 2: Maximum Allowable Lead/Tab Temperature vs. On-State Current

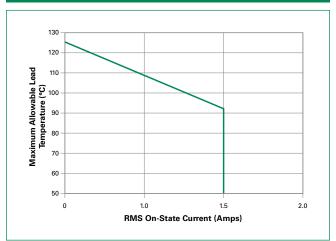


Figure 4: V_{BO} Change vs. Junction Temperature

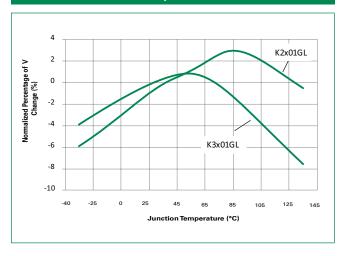


Figure 6: Maximum Allowable Ambient Temperature vs. On-State Current

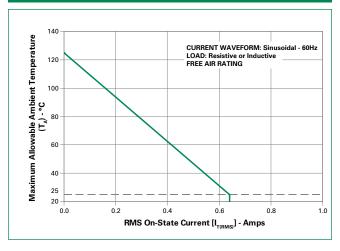
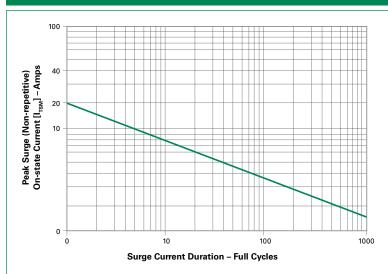




Figure 7: Peak Surge Current vs Surge Current Duration



SUPPLY FREQUENCY: 60 Hz Sinusoidal LOAD: Resistive RMS On-State Current: I_{τ} Maximum Rated Value at Specified Junction Temperature

- 1. Blocking capability may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Figure 8: Typical On-State Voltage vs On-State Current

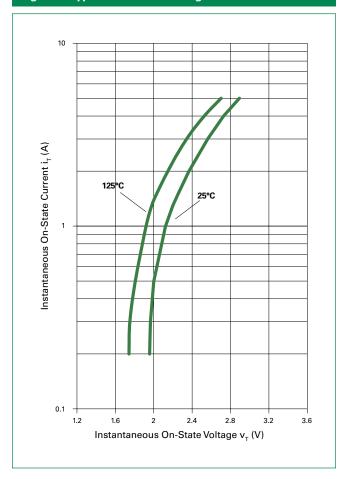
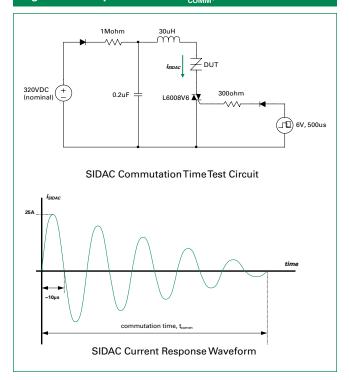


Figure 9: Multipulse[™] SIDAC t_{COMM}, Commutation Time



Additional Information



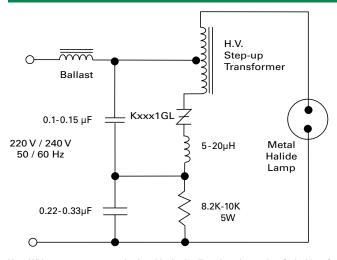




Samples



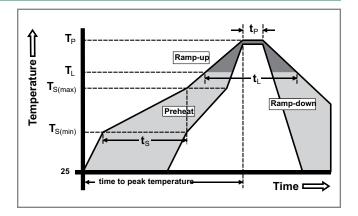
Figure 10: Typical Metal Halide Ignitor Circuit



Note: With proper component selection, this circuit will produce three pulses for ignition of metal halide lamp that requires a minimum of three pulses at 5kV magnitude and >1uSec duration each at a minimum repetition rate of 3.3kHz.

Soldering Parameters

Reflow Condition		Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ramp up rate (Liquidus Temp) (T _L) to peak		5°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max	
	-Temperature (T _L) (Liquidus)	217°C	
Reflow	-Temperature (t _L)	60 – 150 seconds	
PeakTemperature (T _p)		260+0/-5 °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-down Rate		5°C/second max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exceed		280°C	





Physical Specifications

Terminal Finish	100% Matte Tin Plated	
Body Material	UL recognized epoxy meeting flammability classification 94V-0	
Lead Material	Copper Alloy	

Package	Weight / unit (mg)		
DO-15	385		

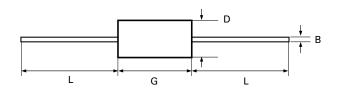
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Overheating and surge currents are the main killers of SIDACs. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

Test	Specifications and Conditions		
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A Rated V _{DRM} (VAC-peak), 125°C, 1008 hours		
Temperature Cycling	MIL-STD-750: Method 1051, 100 cycles; -40°C to 150°C, 15-minute dwell time		
Temperature / Humidity	EIA/JEDEC: JESD22-A101 1008 hours; 160V - DC: 85°C; 85% relative humidity		
High Temp Storage	MIL-STD-750: Method 1031 150°C, 1008 hours		
Low-Temp Storage	-40°C, 1008 hours		
Thermal Shock	MIL-STD-750: Method 1056 10 cycles; 0°C to 100°C; 5-minute dwell- time at each temperature; 10-sec (max) transfer time between temperature		
Autoclave	EIA/JEDEC: JESD22-A102 168 hours (121°C at 2 ATMs) and 100% RH		
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds		
Solderability	ANSI/J-STD-002: Category 3, Test A		
Repetitive Surge Life Testing	Multi firings per half cycle at 60Hz in application circuit for 168 hours minimum		

Dimensions — DO-15 (G Package)



Dimension	Inches		Millimeters	
	Max	Max	Min	Max
В	0.028	0.034	0.711	0.864
D	0.120	0.140	3.048	3.556
G	0.235	0.270	5.969	6.858
L	1.000		25.400	

Product Selector

Part Number	Switching Voltage Range		Blocking Voltage	Packages	
rart Number	V _{BO} Minimum	V _{BO} Maximum	V_{DRM}	rackages	
K2201GL	200V	230V	180V	DO-15	
K2401GL	220V	250V	190V	DO-15	
K2501GL	240V	265V	200V	DO-15	
K3601GL	340V	380V	270V	DO-15	

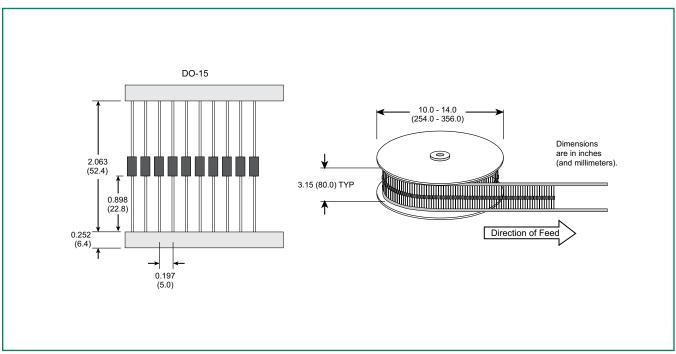
Packing Options

Part Number	Package	Packing Mode	Base Quantity
Kxxx1GL	DO-15	Bulk	1000
Kxxx1GLRP		Tape & Reel	5000

Note: xxx = voltage

DO-15 Embossed Carrier RP Specifications

Meets all EIA RS-29-6 Standards



Part Numbering System

K 220 1 G L RP **SERIES** K: Sidac VOLTAGE PACKAGING OPTIONS 220: 200 to 230V Blank: Bulk 240: 220 to 250V 250: 240 to 265V RP: Tape and Reel 360: 340 to 380V INCREASED H.V. CIRCUIT FUNCTION **GENERATION CAPABILITY** 1: Multipulse" **DEVICE PACKAGE** G: DO-15

Part Marking System



单击下面可查看定价,库存,交付和生命周期等信息

>>Littelfuse(美国力特)